

IELe — bipolar transistors

Petr Veigend

iveigend AT fit.vutbr.cz



Vysoké učení technické v Brně,

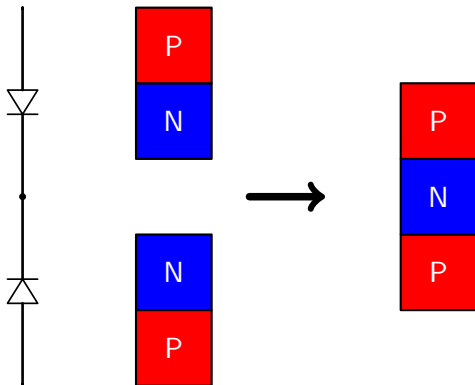
Fakulta informačních technologií, Božetěchova 2, 61266 Brno



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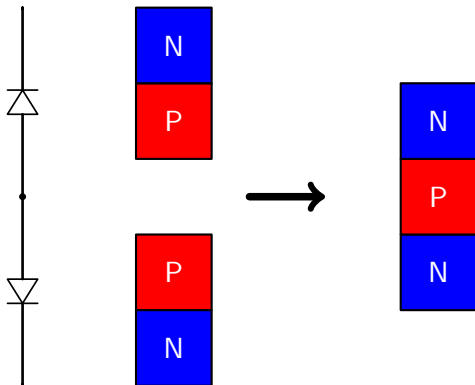
Remember diode

- boxed PN junction, two electrodes (anode – P, cathode – N)
- symbol:  anode —  — cathode
- diode is non linear, possible graphical solution
- we can combine diodes together to form more advanced components – bipolar transistors



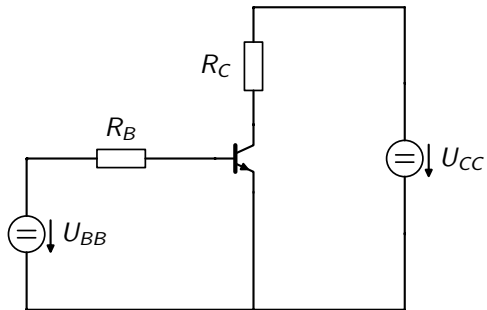
Result — **PNP transistor**

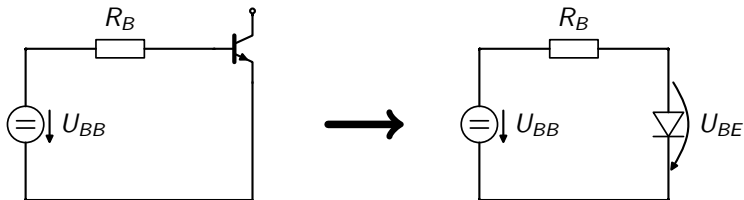




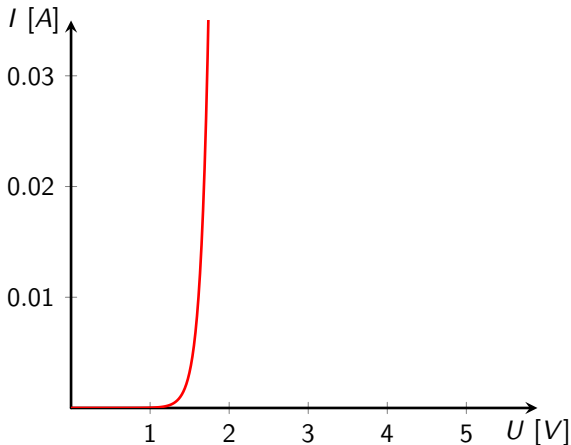
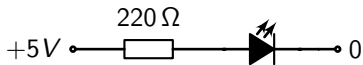
Result — **NPN transistor**

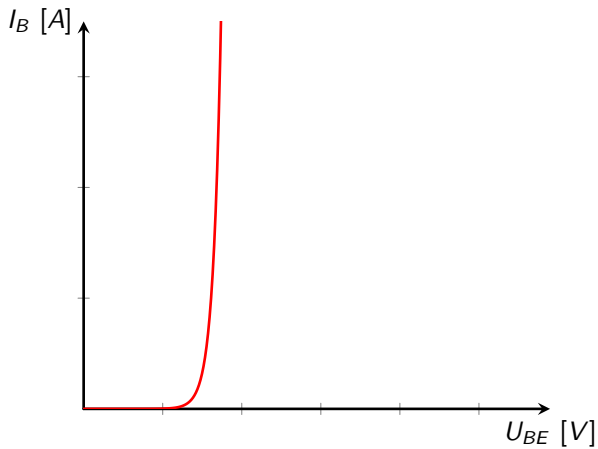


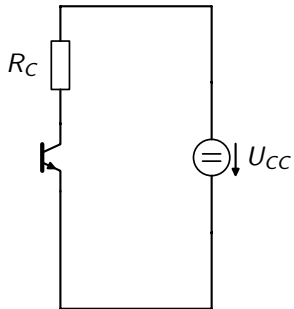


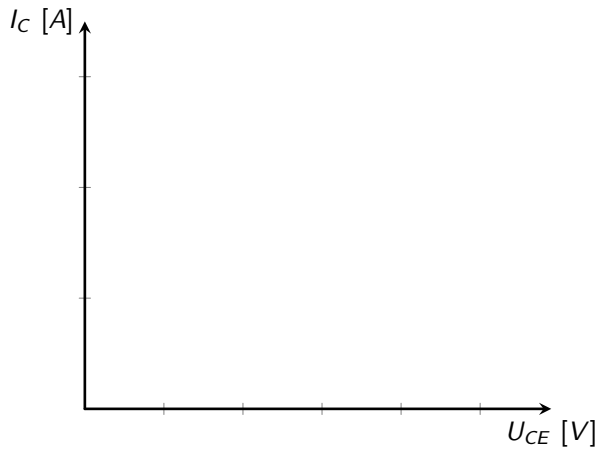


Just a reminder about the graphical solution of the diode:

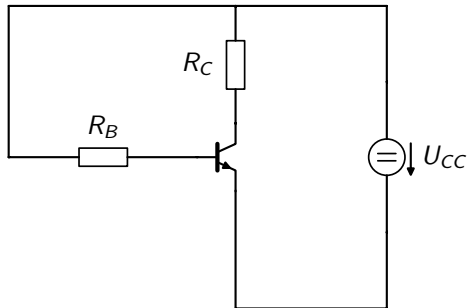


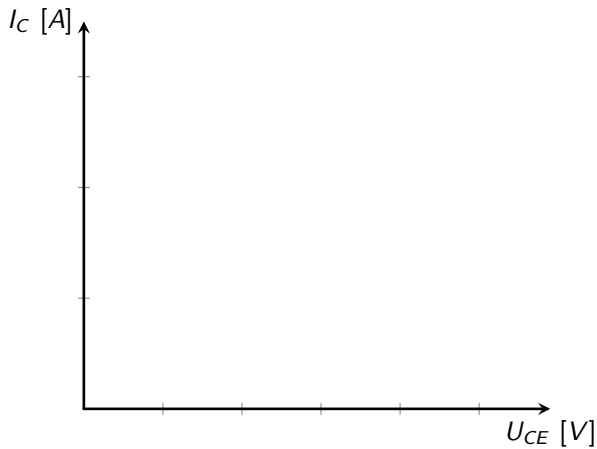




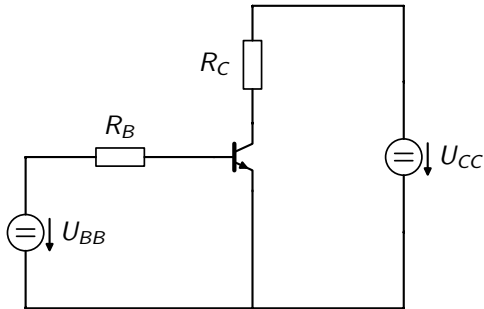


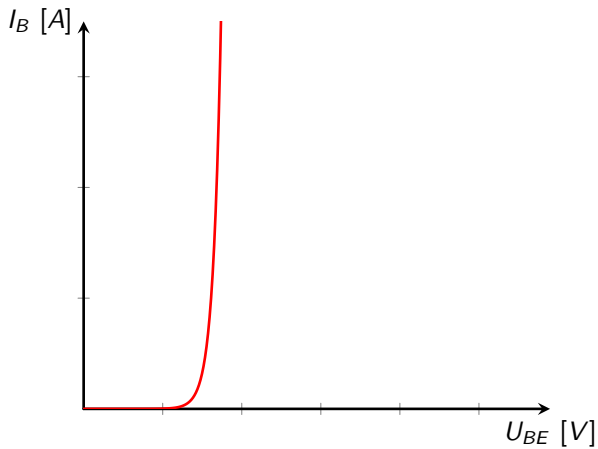
Slightly different circuit

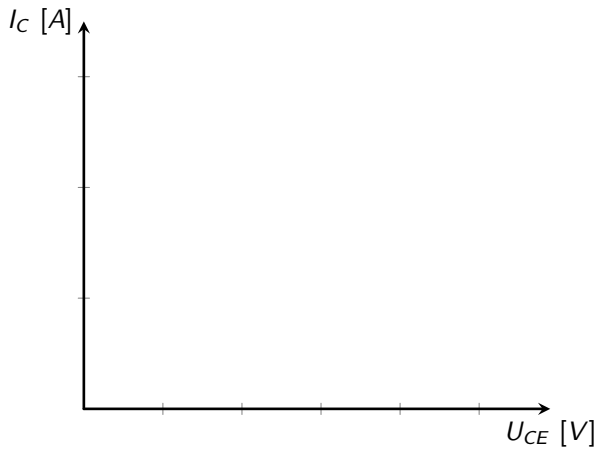


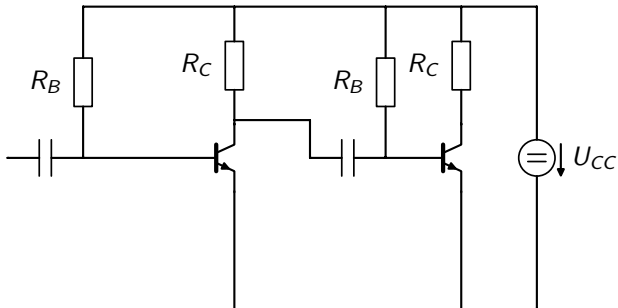


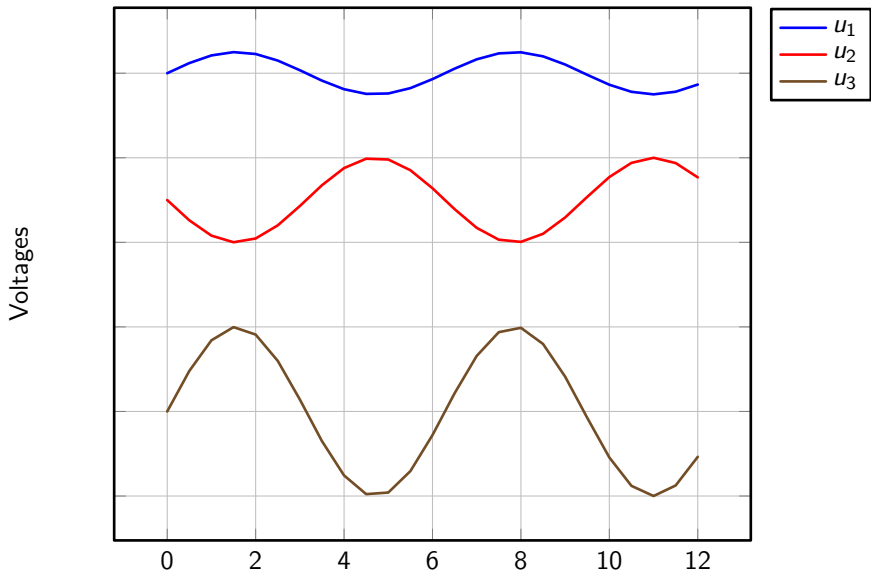
Transistor gain $A = \frac{\Delta U_{CE}}{\Delta U_{BB}}$

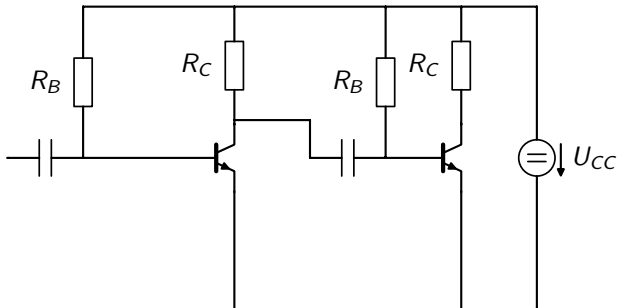


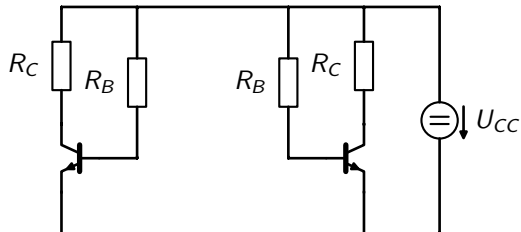












Conclusion:

- bipolar transistor
- solution of the bipolar transistor
- gain of the bipolar transistor
- multi vibrators